

HMC416LP4 / 416LP4E

v02.0805

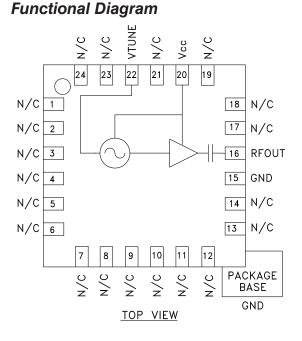


MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- Wireless Infrastructure
- Industrial Controls
- Test Equipment
- Military



Features

Pout: +4.5 dBm

Phase Noise: -114 dBc/Hz @100 k Hz

No External Resonator Needed

Single Supply: 3V @ 37 mA

QFN Leadless SMT Package, 16 mm²

General Description

The HMC416LP4 & HMC416LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 2.75 to 3.0 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.5 dBm typical from a single supply of 3V @ 37 mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4 x 4 mm surface mount package.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = +3V

Parameter	Min.	Тур.	Max.	Units
Frequency Range	2.75 - 3.0		GHz	
Power Output	1.5	4.5		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-114		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3.0V)		37		mA
Tune Port Leakage Current			10	μA
Output Return Loss		9		dB
Harmonics 2nd 3rd		-5 -16		dBc dBc
Pulling (into a 2.0:1 VSWR)		3		MHz pp
Pushing @ Vtune= +5V		-1		MHz/V
Frequency Drift Rate		0.3		MHz/°C

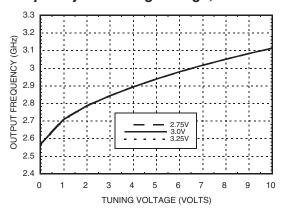
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



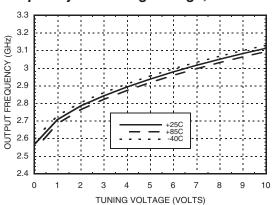


MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz

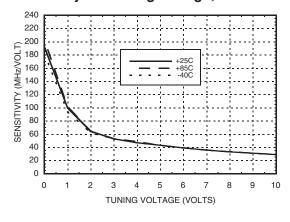
Frequency vs. Tuning Voltage, T= 25°C



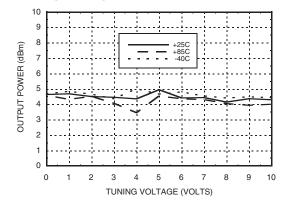
Frequency vs. Tuning Voltage, Vcc= +3V



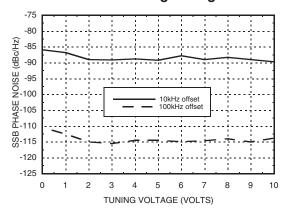
Sensitivity vs. Tuning Voltage, Vcc= +3V



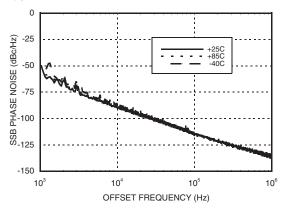
Output Power vs. Tuning Voltage, Vcc= +3V



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V



MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz



Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +11V
Channel Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 3.6 mW/°C above 85°C)	180 mW
Thermal Resistance (R _{TH}) (junction to package base)	277 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vcc

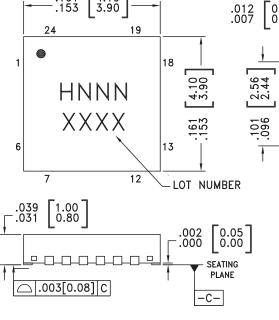
Vcc (V)	Icc (mA)
2.75	32
3.0	37
3.25	42

Note: VCO will operate over full voltage range shown above.

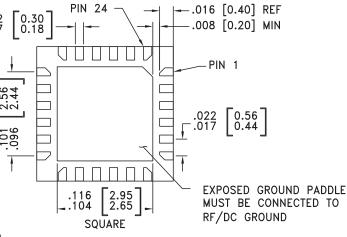


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



BOTTOM VIEW



- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC416LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H416 XXXX
HMC416LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H416 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection. These pins may be connected to RF ground. Performance will not be affected.	
15	GND	This pin must be connected to RF & DC ground.	GND =
16	RFOUT	RF output (AC coupled)	— —○ RFOUT
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE 0
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	GND =

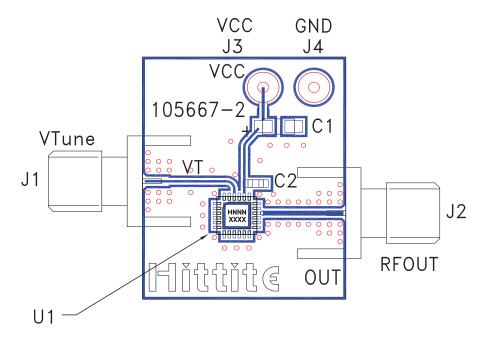


RoHS√

v02.0805

MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz

Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	4.7 μF Tantalum Capacitor
C2	10,000 pF Capacitor, 0603 Pkg.
U1	HMC416LP4 / HMC416LP4E VCO
PCB [2]	105667 Eval Board

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350





Notes:

MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz